SEMICONDUCTOR

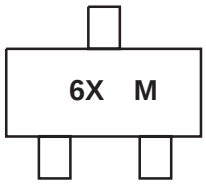
DATA SHEET

MUN511 Series

Bias Resistor Transistor

PNP Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

SOT–323 (SC–70)

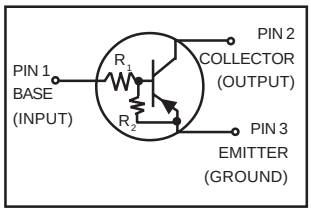


6 X =Specific Device Code
X =(See Marking Table)
M =Date Code

MARKING DIAGRAM

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base–emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SC–70/SOT–323 package which is designed for low power surface mount applications.

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- The SC–70/SOT–323 package can be soldered using wave or reflow. The modified gull–winged leads absorb thermal stress during soldering eliminating the possibility of damage to the die.



MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	Vdc
Collector-Emitter Voltage	V_{CEO}	50	Vdc
Collector Current	I_C	100	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation	P_D	202 (Note 1)	mW
T_A = 25°C		310 (Note 2)	
Derate above 25°C		1.6 (Note 1)	°C/W
		2.5 (Note 2)	
Thermal Resistance –	$R_{\theta JA}$	618 (Note 1)	°C/W
Junction-to-Ambient		403 (Note 2)	
Thermal Resistance –	$R_{\theta JL}$	280 (Note 1)	°C/W
Junction-to-Lead		332 (Note 2)	
Junction and Storage	T_J, T_{stg}	–55 to +150	°C
Temperature Range			

1. FR–4 @ Minimum Pad
2. FR–4 @ 1.0 x 1.0 inch Pad

DEVICE MARKING AND RESISTOR VALUES

Device	Package	Marking	R1 (K)	R2 (K)	Shipping
MUN5111	SC–70/SOT–323	6A	10	10	3000/Tape & Reel
MUN5112	SC–70/SOT–323	6B	22	22	3000/Tape & Reel
MUN5113	SC–70/SOT–323	6C	47	47	3000/Tape & Reel
MUN5114	SC–70/SOT–323	6D	10	47	3000/Tape & Reel
MUN5115	SC–70/SOT–323	6E	10	∞	3000/Tape & Reel
MUN5116	SC–70/SOT–323	6F	4.7	∞	3000/Tape & Reel
MUN5130	SC–70/SOT–323	6G	1.0	1.0	3000/Tape & Reel
MUN5131	SC–70/SOT–323	6H	2.2	2.2	3000/Tape & Reel
MUN5132	SC–70/SOT–323	6J	4.7	4.7	3000/Tape & Reel
MUN5133	SC–70/SOT–323	6K	4.7	47	3000/Tape & Reel
MUN5134	SC–70/SOT–323	6L	22	47	3000/Tape & Reel
MUN5135	SC–70/SOT–323	6M	2.2	47	3000/Tape & Reel
MUN5136	SC–70/SOT–323	6N	100	100	3000/Tape & Reel
MUN5137	SC–70/SOT–323	6P	47	22	3000/Tape & Reel

3. New devices. Updated curves to follow in subsequent data sheets.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Collector–Base Cutoff Current (V_{CB} = 50 V, I_E = 0)		I_{CBO}	–	–	100	nAdc
Collector–Emitter Cutoff Current (V_{CE} = 50 V, I_B = 0)		I_{CEO}	–	–	500	nAdc
Emitter–Base Cutoff Current	MUN5111	I_{EBO}	–	–	0.5	mAdc
(V_{EB} = 6.0 V, I_C = 0)	MUN5112		–	–	0.2	
	MUN5113		–	–	0.1	
	MUN5114		–	–	0.2	
	MUN5115		–	–	0.9	
	MUN5116		–	–	1.9	
	MUN5130		–	–	4.3	
	MUN5131		–	–	2.3	
	MUN5132		–	–	1.5	
	MUN5133		–	–	0.18	
	MUN5134		–	–	0.13	
	MUN5135		–	–	0.2	
	MUN5136		–	–	0.05	
	MUN5137		–	–	0.13	
Collector–Base Breakdown Voltage (I_C = 10 μA, I_E = 0)		$V_{(BR)CBO}$	50	–	–	Vdc
Collector–Emitter Breakdown Voltage (Note 4) (I_C = 2.0 mA, I_B = 0)		$V_{(BR)CEO}$	50	–	–	Vdc
ON CHARACTERISTICS (Note 4)						
DC Current Gain	MUN5111	h_{FE}	35	60	–	
(V_{CE} = 10 V, I_C = 5.0 mA)	MUN5112		60	100	–	
	MUN5113		80	140	–	
	MUN5114		80	140	–	
	MUN5115		160	250	–	
	MUN5116		160	250	–	
	MUN5130		3.0	5.0	–	
	MUN5131		8.0	15	–	
	MUN5132		15	27	–	
	MUN5133		80	140	–	
	MUN5134		80	130	–	
	MUN5135		80	140	–	
	MUN5136		80	150	–	
	MUN5137		80	140	–	
Collector–Emitter Saturation Voltage (I_C = 10 mA, I_E = 0.3 mA) (I_C = 10 mA, I_B = 5 mA) MUN5130T1/MUN5131T1 (I_C = 10 mA, I_B = 1 mA) MUN5115T1/MUN5116T1/ MUN5132T1/MUN5133T1/MUN5134T1		$V_{CE(sat)}$	–	–	0.25	Vdc
Output Voltage (on)		V_{OL}				Vdc
(V_{CC} = 5.0 V, V_B = 2.5 V, R_L = 1.0 kΩ)	MUN5111		–	–	0.2	
	MUN5112		–	–	0.2	
	MUN5114		–	–	0.2	
	MUN5115		–	–	0.2	
	MUN5116		–	–	0.2	
	MUN5130		–	–	0.2	
	MUN5131		–	–	0.2	
	MUN5132		–	–	0.2	
	MUN5133		–	–	0.2	
	MUN5134		–	–	0.2	
	MUN5135		–	–	0.2	
(V_{CC} = 5.0 V, V_B = 3.5 V, R_L = 1.0 kΩ)	MUN5113		–	–	0.2	
(V_{CC} = 5.0 V, V_B = 5.5 V, R_L = 1.0 kΩ)	MUN5136		–	–	0.2	
(V_{CC} = 5.0 V, V_B = 4.0 V, R_L = 1.0 kΩ)	MUN5137		–	–	0.2	

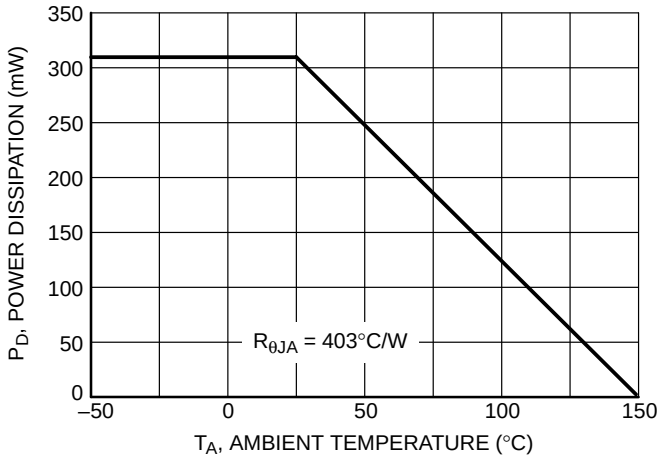
4. Pulse Test: Pulse Width < 300 μs, Duty Cycle < 2.0%

DEVICE CHARACTERISTICS

MUN511 Series

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Typ	Max	Unit
Output Voltage (off) (V_{CC} = 5.0 V, V_B = 0.5 V, R_L = 1.0 kΩ) (V_{CC} = 5.0 V, V_B = 0.050 V, R_L = 1.0 kΩ) MUN5130 (V_{CC} = 5.0 V, V_B = 0.25 V, R_L = 1.0 kΩ) MUN5115 MUN5116 MUN5131 MUN5132		V_{OH}	4.9	–	–	Vdc
Input Resistor	MUN5111	R1	7.0	10	13	kΩ
	MUN5112		15.4	22	28.6	
	MUN5113		32.9	47	61.1	
	MUN5114		7.0	10	13	
	MUN5115		7.0	10	13	
	MUN5116		3.3	4.7	6.1	
	MUN5130		0.7	1.0	1.3	
	MUN5131		1.5	2.2	2.9	
	MUN5132		3.3	4.7	6.1	
	MUN5133		3.3	4.7	6.1	
	MUN5134		15.4	22	28.6	
	MUN5135		1.54	2.2	2.86	
	MUN5136		70	100	130	
	MUN5137		32.9	47	61.1	
Resistor Ratio	MUN5111T1/MUN5112T1/MUN5113T1/ MUN5136	R_1/R_2	0.8	1.0	1.2	
	MUN5114		0.17	0.21	0.25	
	MUN5115/MUN5116		–	–	–	
	MUN5130/MUN5131/MUN5132		0.8	1.0	1.2	
	MUN5133		0.055	0.1	0.185	
	MUN5134		0.38	0.47	0.56	
	MUN5135		0.038	0.047	0.056	
	MUN5137		1.7	2.1	2.6	



DEVICE CHARACTERISTICS

MUN511 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN5111

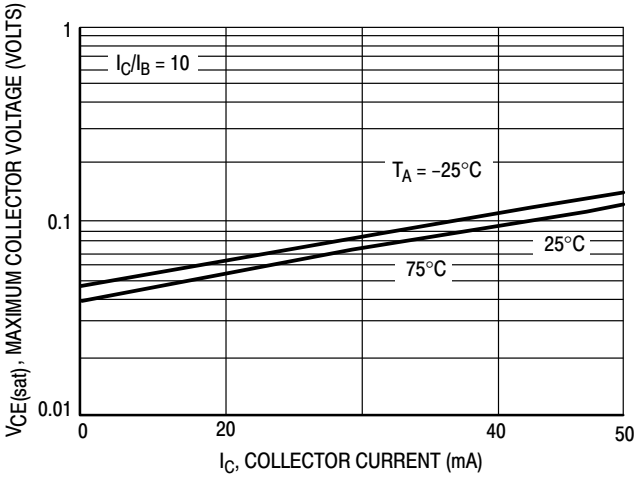


Figure 2. $V_{CE(sat)}$ versus I_C

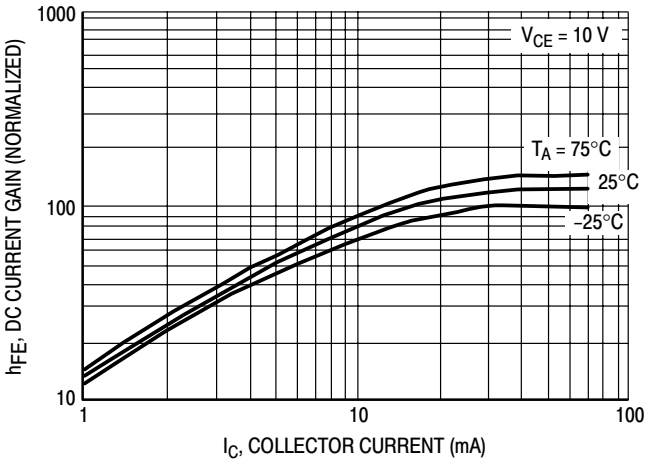


Figure 3. DC Current Gain

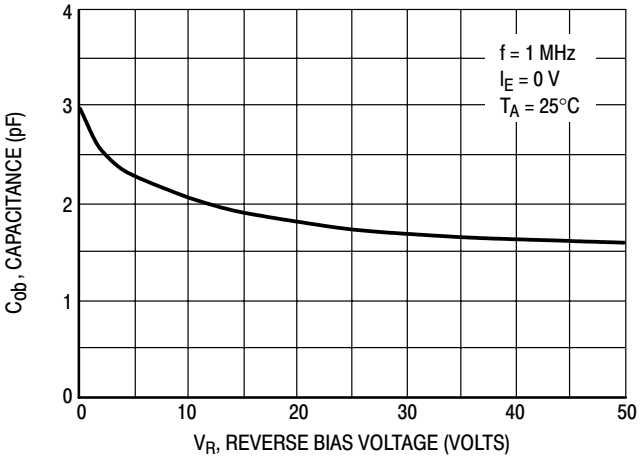


Figure 4. Output Capacitance

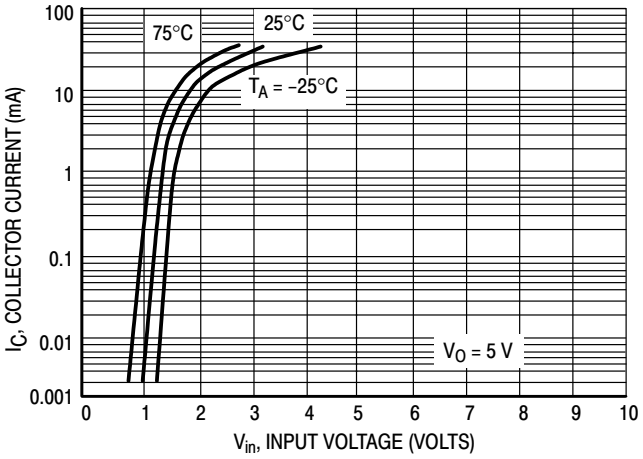


Figure 5. Output Current versus Input Voltage

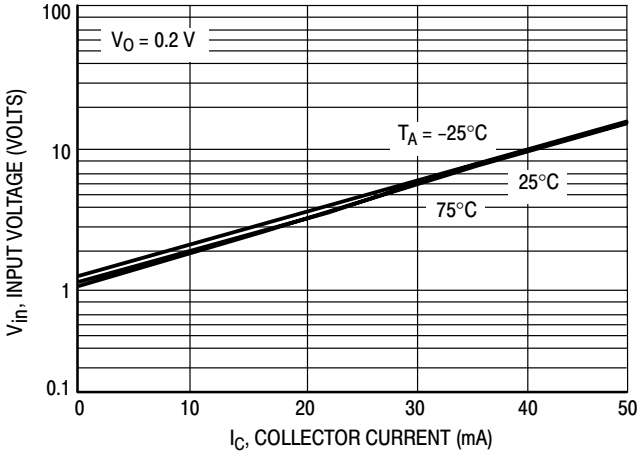


Figure 6. Input Voltage versus Output Current

DEVICE CHARACTERISTICS

MUN511 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN5112

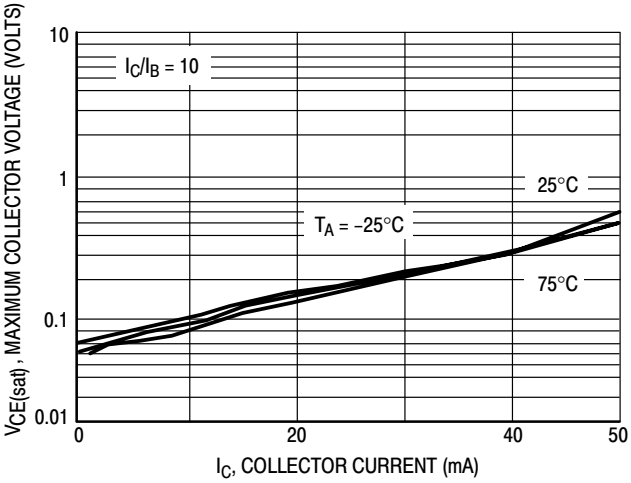


Figure 7. $V_{CE(sat)}$ versus I_C

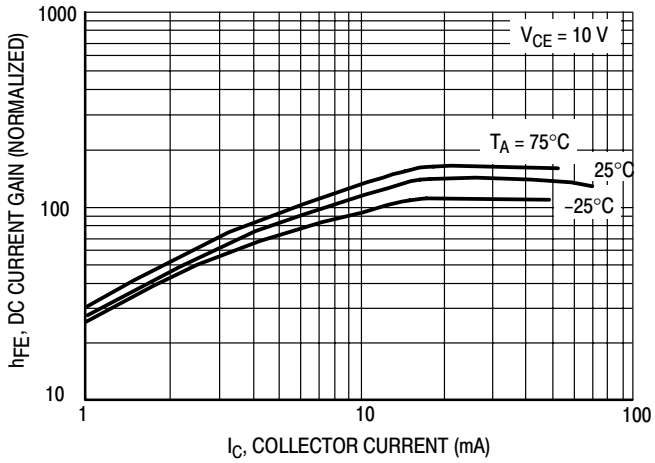


Figure 8. DC Current Gain

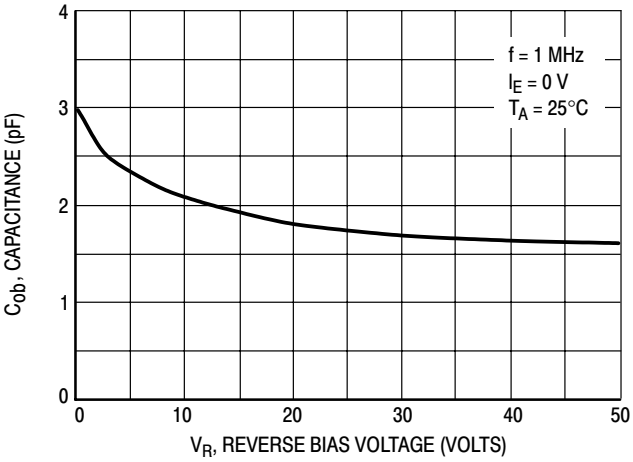


Figure 9. Output Capacitance

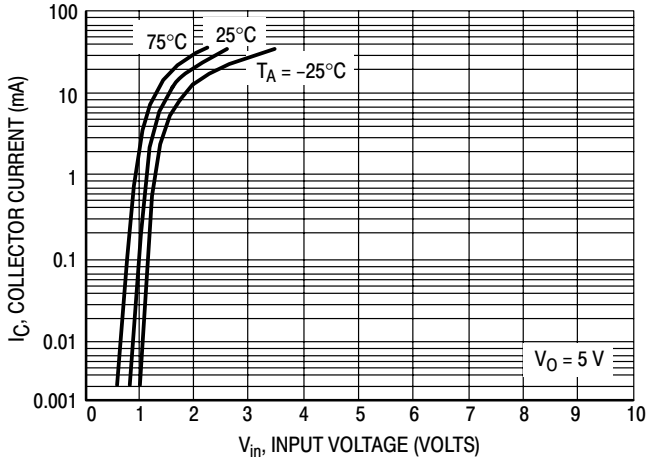


Figure 10. Output Current versus Input Voltage

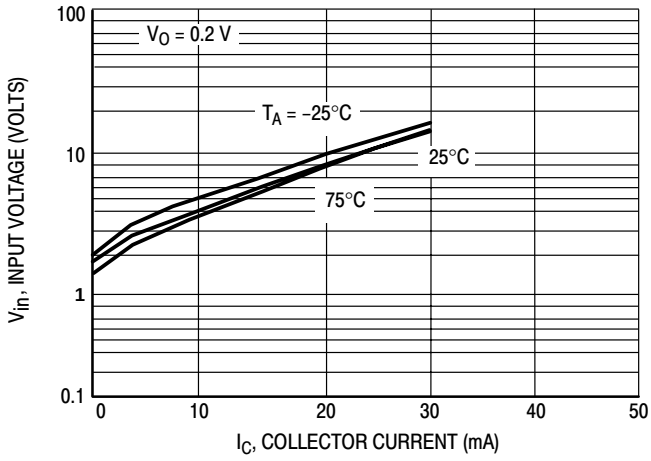


Figure 11. Input Voltage versus Output Current

DEVICE CHARACTERISTICS

MUN511 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN5113

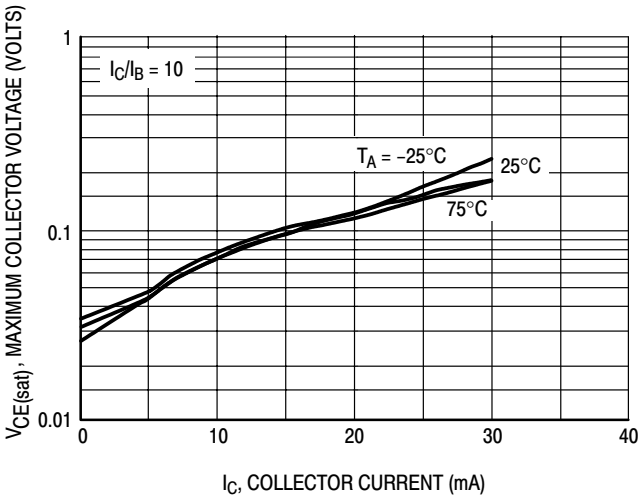


Figure 12. $V_{CE(sat)}$ versus I_C

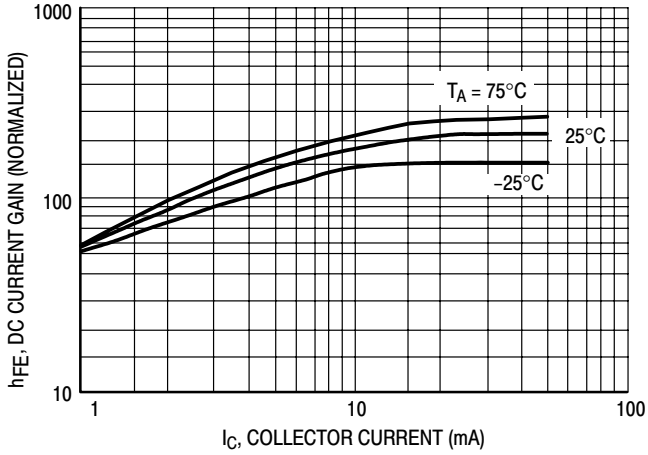


Figure 13. DC Current Gain

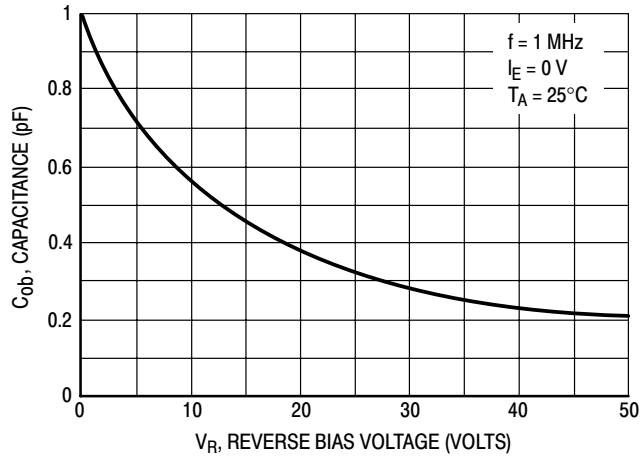


Figure 14. Output Capacitance

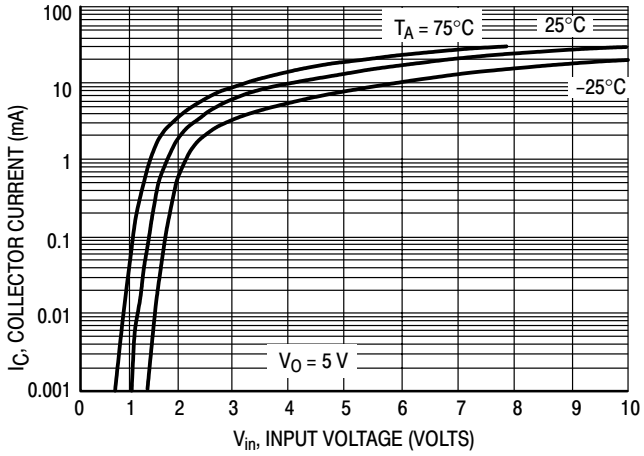


Figure 15. Output Current versus Input Voltage

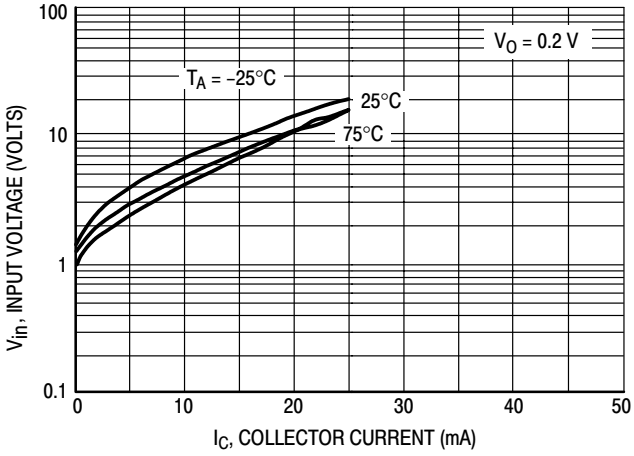


Figure 16. Input Voltage versus Output Current

TYPICAL ELECTRICAL CHARACTERISTICS – MUN5114

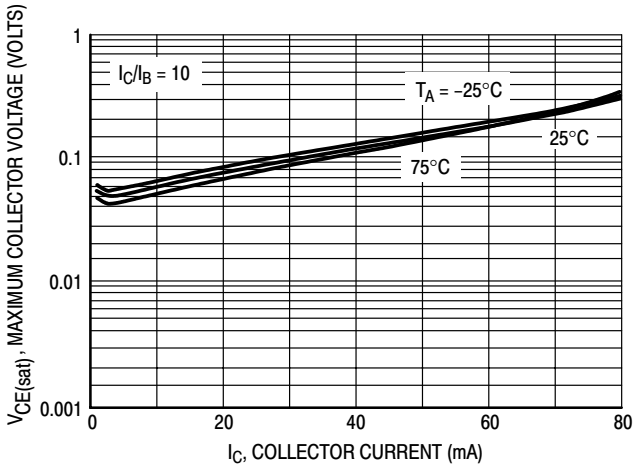


Figure 17. $V_{CE(sat)}$ versus I_C

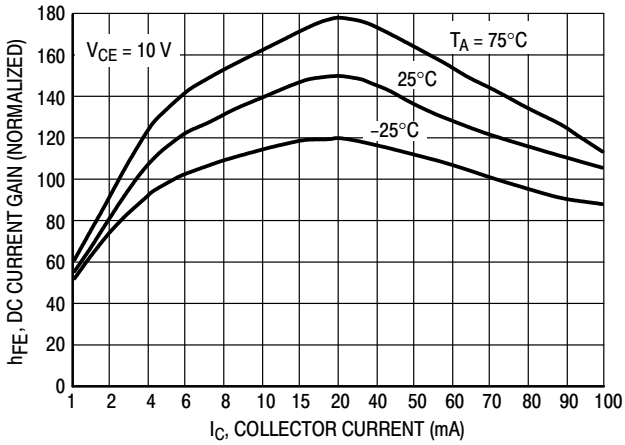


Figure 18. DC Current Gain

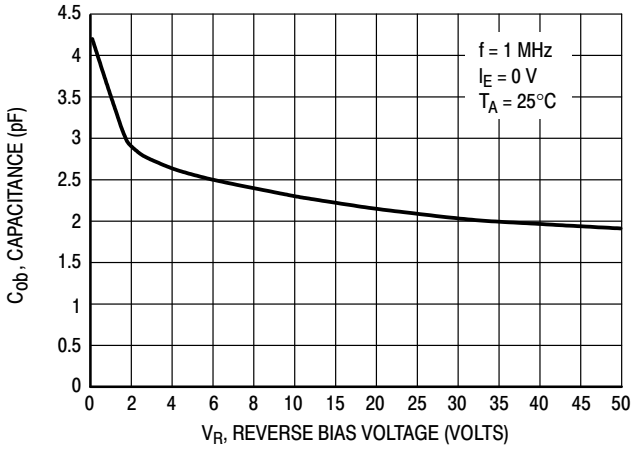


Figure 19. Output Capacitance

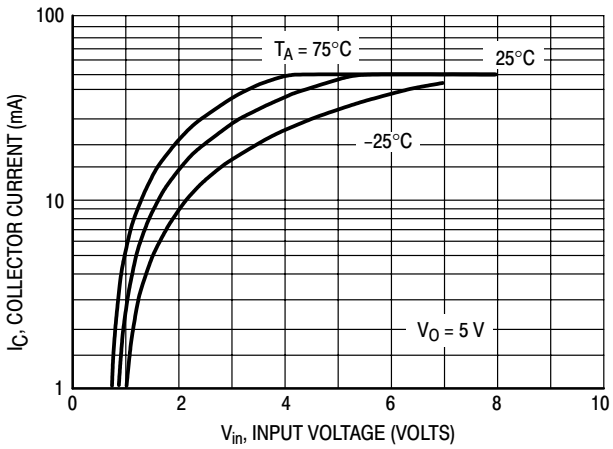


Figure 20. Output Current versus Input Voltage

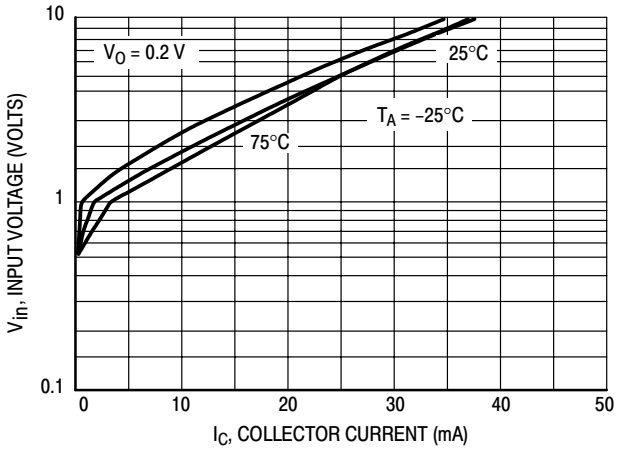


Figure 21. Input Voltage versus Output Current

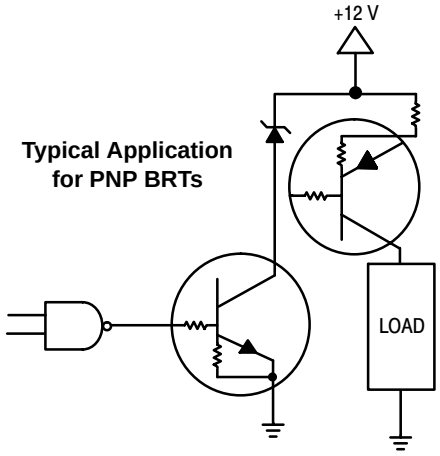


Figure 22. Inexpensive, Unregulated Current Source

DEVICE CHARACTERISTICS

MUN511 Series

TYPICAL ELECTRICAL CHARACTERISTICS — MUN5132

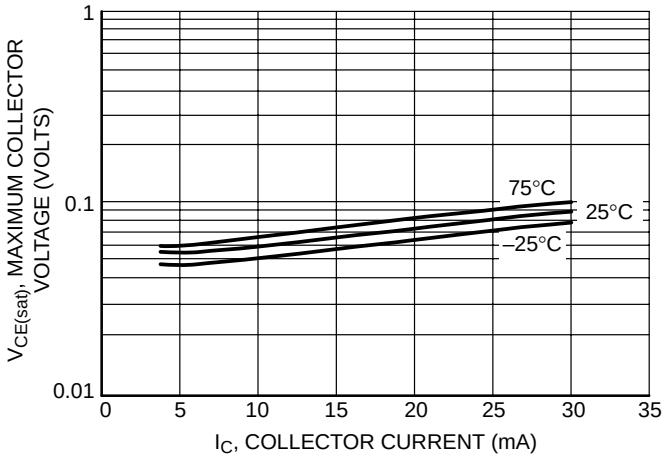


Figure 23. Maximum Collector Voltage versus Collector Current

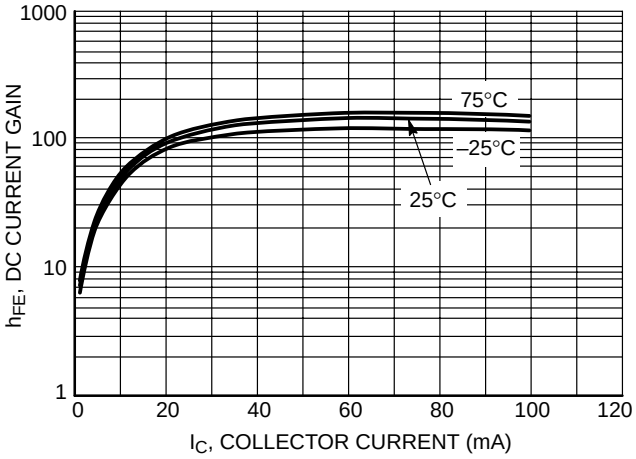


Figure 24. DC Current Gain

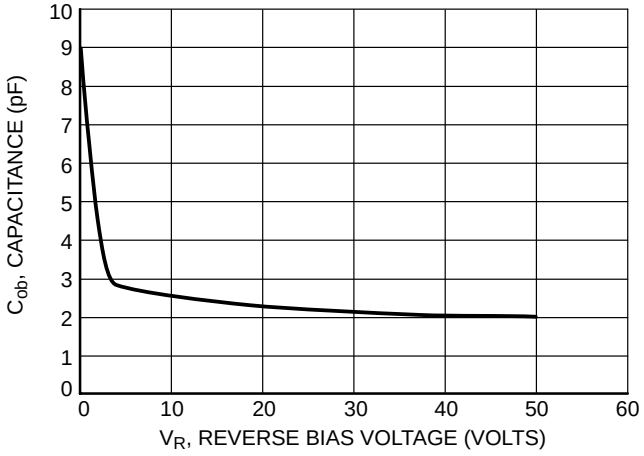


Figure 25. Output Capacitance

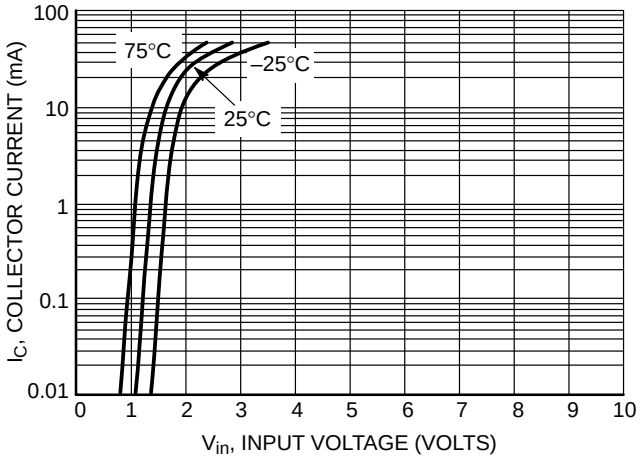


Figure 26. Output Current versus Input Voltage

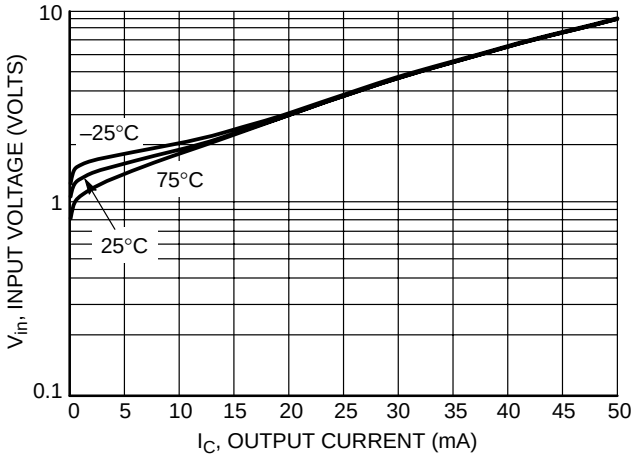


Figure 27. Input Voltage versus Output Current

DEVICE CHARACTERISTICS

MUN511 Series

TYPICAL ELECTRICAL CHARACTERISTICS — MUN5136

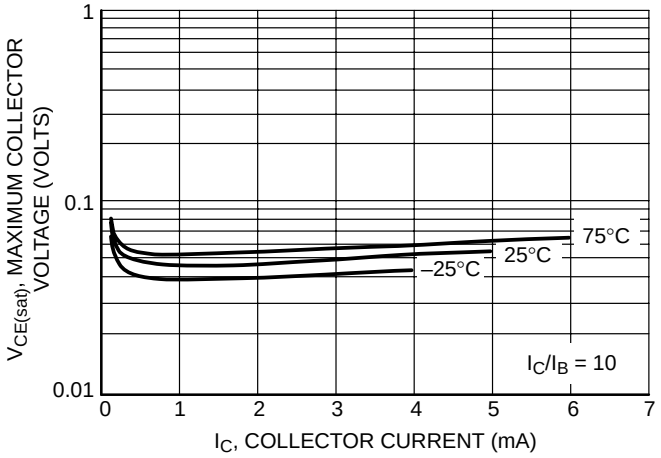


Figure 28. Maximum Collector Voltage versus Collector Current

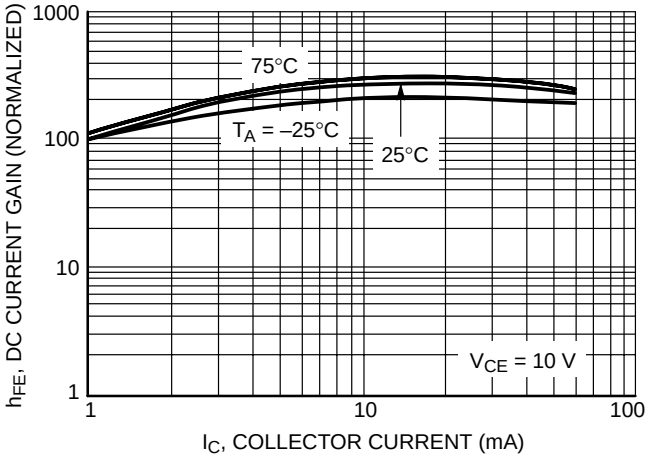


Figure 29. DC Current Gain

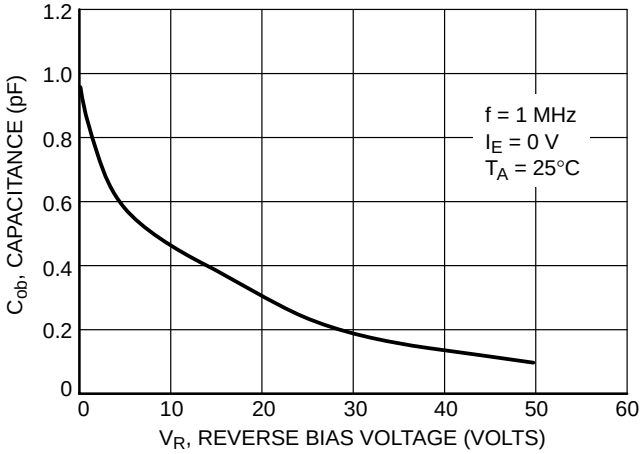


Figure 30. Output Capacitance

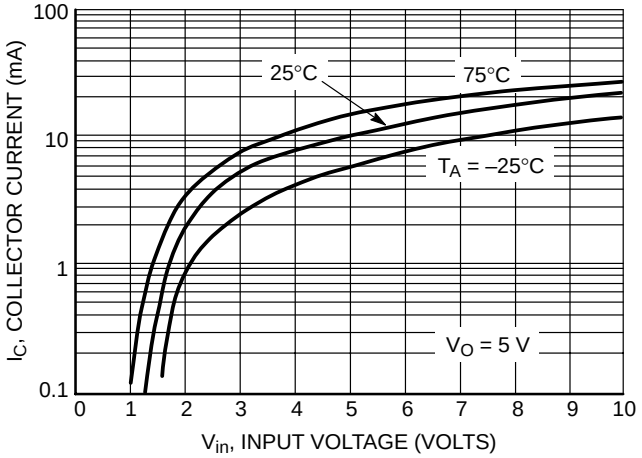


Figure 31. Output Current versus Input Voltage

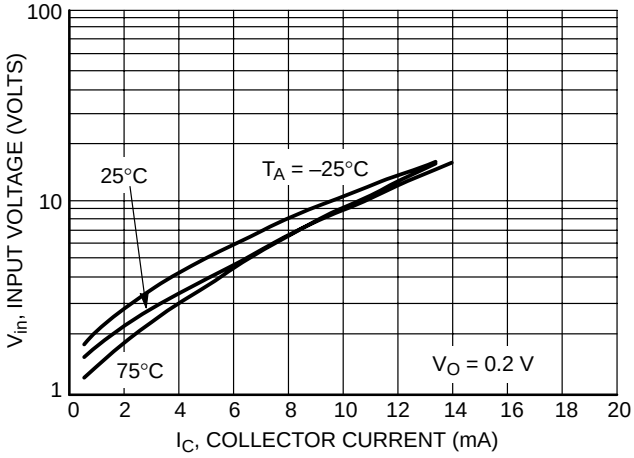


Figure 32. Input Voltage versus Output Current

DEVICE CHARACTERISTICS

MUN511 Series

TYPICAL ELECTRICAL CHARACTERISTICS — MUN5137

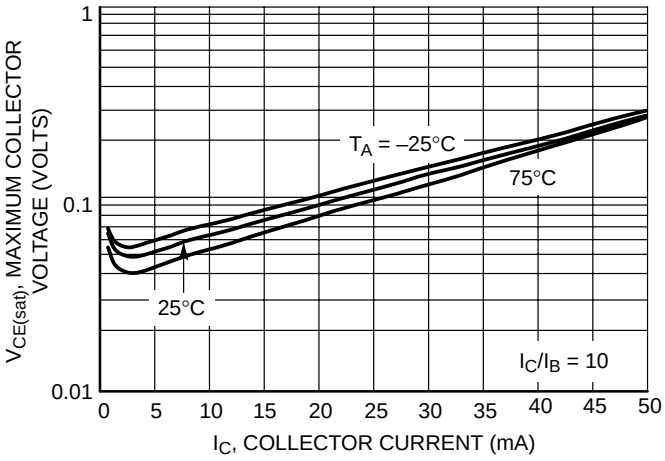


Figure 33. Maximum Collector Voltage versus Collector Current

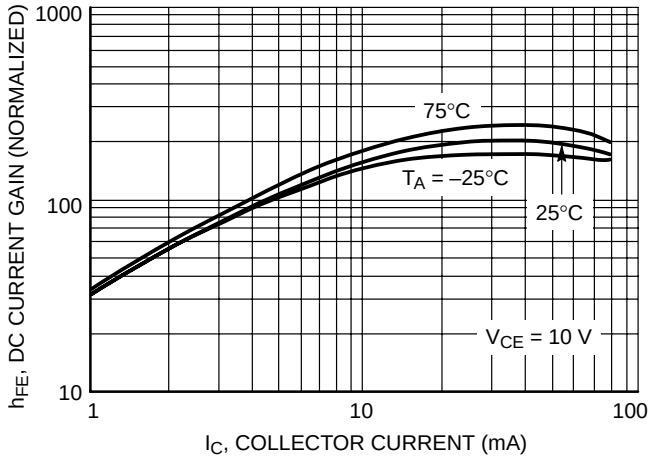


Figure 34. DC Current Gain

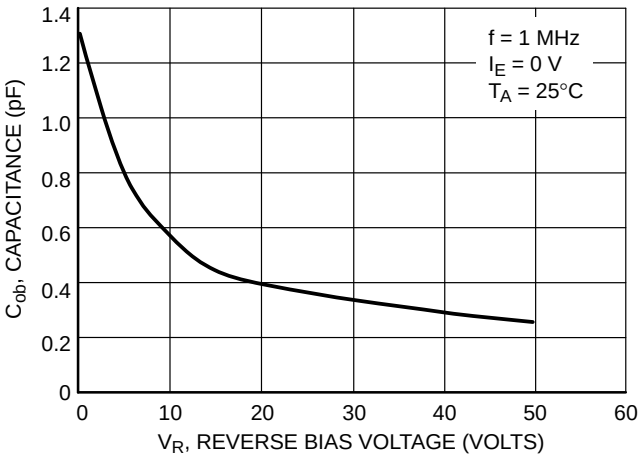


Figure 35. Output Capacitance

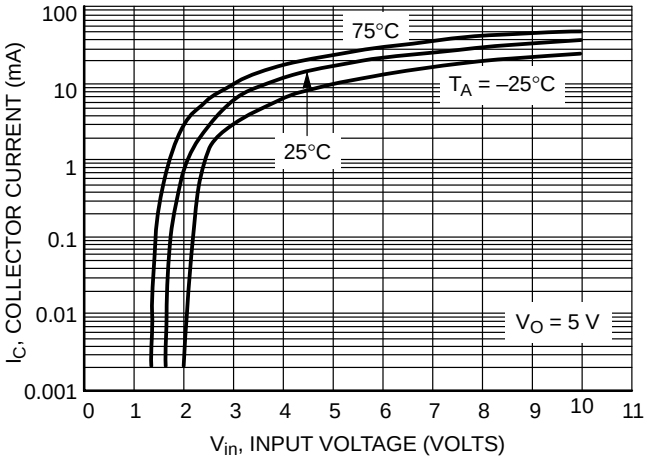


Figure 36. Output Current versus Input Voltage

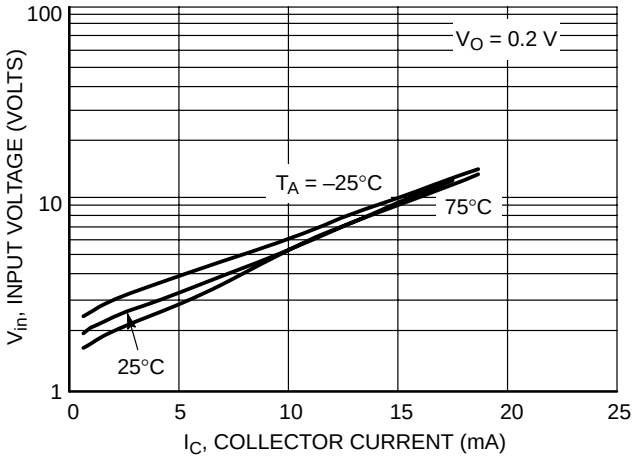


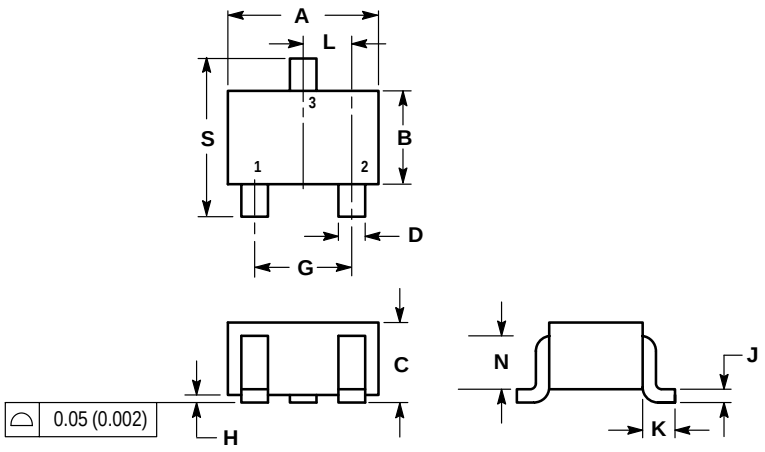
Figure 37. Input Voltage versus Output Current

PACKAGE OUTLINE & DIMENSIONS

MUN511 Series

SC–70 / SOT–323

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.032	0.040	0.80	1.00
D	0.012	0.016	0.30	0.40
G	0.047	0.055	1.20	1.40
H	0.000	0.004	0.00	0.10
J	0.004	0.010	0.10	0.25
K	0.017 REF		0.425 REF	
L	0.026 BSC		0.650 BSC	
N	0.028 REF		0.700 REF	
S	0.079	0.095	2.00	2.40